

STGW30M65DF2

Request a Quote

STGW30M65DF2 Information

	Part Number	STGW30M65DF2
	Manufacturer	STMicroelectronics
www.helsuner.dom	Category	Discrete Semiconductor Products Transistors - IGBTs - Single
	Description	TRENCH GATE FIELD-STOP IGBT M SE
AL /	Package	TO-247-3
1		For the pricing/inventory/lead time, please contact us
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



STGW30M65DF2 Specifications

Manufacturer Part Number	STGW30M65DF2
Manufacturer	STMicroelectronics
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-247-3
Series	-
IGBT Type	Trench Field Stop
Voltage - Collector Emitter Breakdown (Max)	650V
Current - Collector (Ic) (Max)	60A
Current - Collector Pulsed (Icm)	120A
Vce(on) (Max) @ Vge, Ic	2V @ 15V, 30A
Power - Max	258W
Switching Energy	300µJ (on), 960µJ (off)
Input Type	Standard
Gate Charge	80nC
Td (on/off) @ 25°C	31.6ns/115ns
Test Condition	400V, 30A, 10 Ohm, 15V
Reverse Recovery Time (trr)	140ns
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-247-3
Supplier Device Package	TO-247
	Report errors?

STGW30M65DF2 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE ELARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

STGW30M65DF2 Payment Methods





If you have any question about STGW30M65DF2, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com